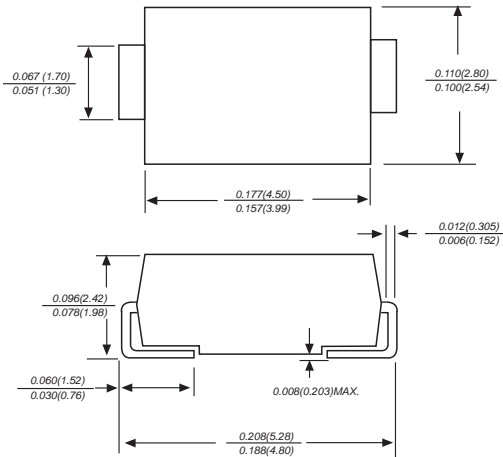




SS32 THRU SS3200

SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER
 Reverse Voltage - 20 to 200 Volts Forward Current - 3.0 Amperes

DO-214AC/SMA



FEATURES

- ◆ The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- ◆ For surface mounted applications
- ◆ Low reverse leakage
- ◆ Built-in strain relief, ideal for automated placement
- ◆ High forward surge current capability
- ◆ High temperature soldering guaranteed: 250°C/10 seconds at terminals

MECHANICAL DATA

Case: JEDEC DO-214AC molded plastic body
Terminals: leads solderable per MIL-STD-750, Method 2026
Polarity: Color band denotes cathode end
Mounting Position: Any
Weight: 0.002 ounce, 0.07 grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.
 Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

MDD Catalog Number	SYMBOLS	SS32	SS33	SS34	SS35	SS36	SS38	SS310	SS3150	SS3200	UNITS	
Marking code		MDD SS32	MDD SS33	MDD SS34	MDD SS35	MDD SS36	MDD SS38	MDD SS310	MDD SS3150	MDD SS3200		
Maximum repetitive peak reverse voltage	V_{RRM}	20	30	40	50	60	80	100	150	200	VOLTS	
Maximum RMS voltage	V_{RMS}	14	21	28	35	42	56	70	105	150	VOLTS	
Maximum DC blocking voltage	V_{DC}	20	30	40	50	60	80	100	150	200	VOLTS	
Maximum average forward rectified current at T_L (see fig.1)	$I_{(AV)}$	3.0									Amps	
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	100.0									Amps	
Maximum instantaneous forward voltage at 3.0A	V_F	0.55			0.70		0.85		0.95		Volts	
Maximum DC reverse current at rated DC blocking voltage	I_R	0.5						0.2		mA		
$T_A=25^\circ C$ $T_A=100^\circ C$		20				10		2.0				
Typical junction capacitance (NOTE 1)	C_J	500			300						pF	
Typical thermal resistance (NOTE 2)	$R_{\theta JA}$	55.0										°C/W
Operating junction temperature range	T_J	-50 to +125						-50 to +150				°C
Storage temperature range	T_{STG}	-50 to +150										°C

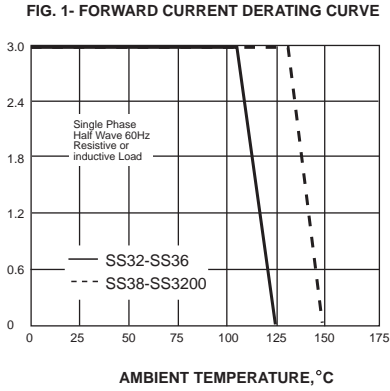
Note: 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
 2. P.C.B. mounted with 0.2x0.2" (5.0x5.0mm) copper pad areas



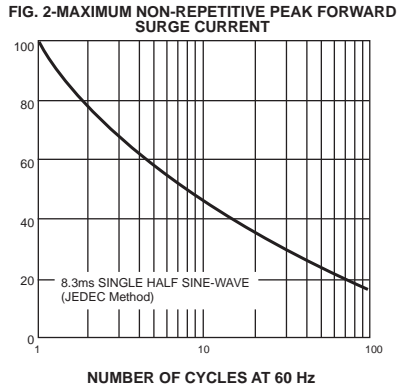
www.microdiode.com

RATINGS AND CHARACTERISTIC CURVES SS32 THRU SS3200

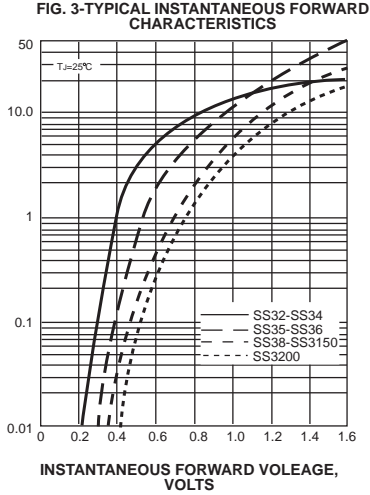
AVERAGE FORWARD RECTIFIED CURRENT, AMPERES



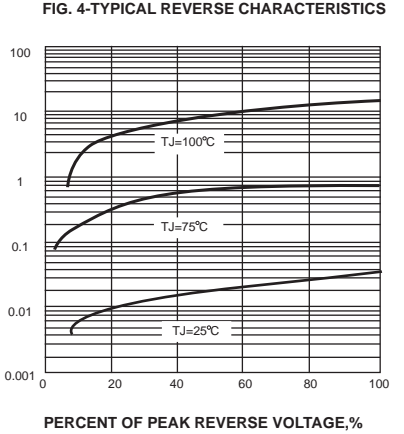
PEAK FORWARD SURGE CURRENT, AMPERES



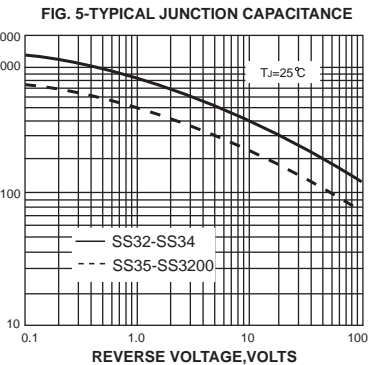
INSTANTANEOUS FORWARD CURRENT, AMPERES



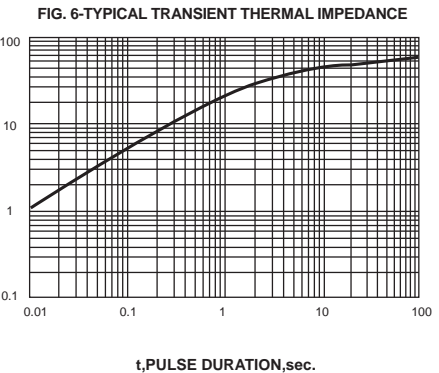
INSTANTANEOUS REVERSE CURRENT, MILLIAMPERES



JUNCTION CAPACITANCE, pF



TRANSIENT THERMAL IMPEDANCE, °C/W



The cruve graph is for reference only, can't be the basis for judgment(曲线图仅供参考!)

